

MOSFETs Silicon N-Channel MOS (DTMOSIV)

# **TK49N65W**

#### 1. Applications

• Switching Voltage Regulators

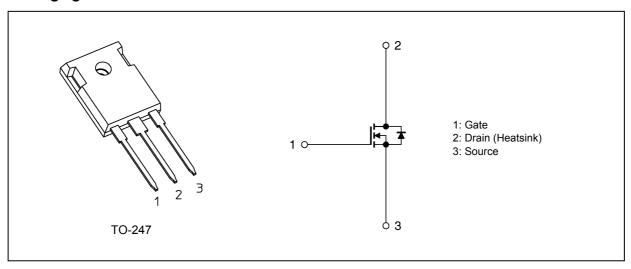
#### 2. Features

(1) Low drain-source on-resistance:  $R_{DS(ON)}$  = 0.048  $\Omega$  (typ.) by using Super Junction Structure: DTMOS

(2) Easy to control Gate switching

(3) Enhancement mode:  $V_{th}$  = 2.5 to 3.5 V ( $V_{DS}$  = 10 V,  $I_D$  = 2.5 mA)

#### 3. Packaging and Internal Circuit



## 4. Absolute Maximum Ratings (Note) (T<sub>a</sub> = 25°C unless otherwise specified)

Characteristics	Symbol	Rating	Unit	
Drain-source voltage		$V_{DSS}$	650	V
Gate-source voltage		V <sub>GSS</sub>	±30	7
Drain current (DC)	(Note 1)	I <sub>D</sub>	49.2	Α
Drain current (pulsed)	(Note 1)	I <sub>DP</sub>	196	7
Power dissipation (T <sub>c</sub> = 25°C)		P <sub>D</sub>	400	W
Single-pulse avalanche energy	(Note 2)	E <sub>AS</sub>	764	mJ
Avalanche current		I <sub>AR</sub>	13	Α
Reverse drain current (DC)	(Note 1)	I <sub>DR</sub>	49.2	1
Reverse drain current (pulsed)	(Note 1)	I <sub>DRP</sub>	196	1
Channel temperature		T <sub>ch</sub>	150	℃
Storage temperature		T <sub>stg</sub>	-55 to 150	
Mounting torque		TOR	0.8	N · m

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Start of commercial production



#### 5. Thermal Characteristics

Characteristics	Symbol	Max	Unit
Channel-to-case thermal resistance	R <sub>th(ch-c)</sub>	0.313	°C/W
Channel-to-ambient thermal resistance	R <sub>th(ch-a)</sub>	50	

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2:  $V_{DD}$  = 90 V,  $T_{ch}$  = 25°C (initial), L = 8 mH,  $R_{G}$  = 25  $\Omega,\,I_{AR}$  = 13 A

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.

#### 6. Electrical Characteristics

# 6.1. Static Characteristics (T<sub>a</sub> = 25°C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current	I <sub>GSS</sub>	$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0 \text{ V}$	-	_	±1	μА
Drain cut-off current	I <sub>DSS</sub>	V <sub>DS</sub> = 650 V, V <sub>GS</sub> = 0 V	1		10	
Drain-source breakdown voltage	V <sub>(BR)DSS</sub>	I <sub>D</sub> = 10 mA, V <sub>GS</sub> = 0 V	650	_	_	V
Gate threshold voltage	$V_{th}$	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 2.5 mA	2.5	_	3.5	
Drain-source on-resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 24.6 A	1	0.048	0.055	Ω

### 6.2. Dynamic Characteristics (T<sub>a</sub> = 25°C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Input capacitance	C <sub>iss</sub>	V <sub>DS</sub> = 300 V, V <sub>GS</sub> = 0 V, f = 100 kHz	_	6500	_	pF
Reverse transfer capacitance	C <sub>rss</sub>		_	15	_	
Output capacitance	C <sub>oss</sub>		_	140	_	
Effective output capacitance	C <sub>o(er)</sub>	V <sub>DS</sub> = 0 to 400 V, V <sub>GS</sub> = 0 V	_	200	_	
Gate resistance	r <sub>g</sub>	V <sub>DS</sub> = OPEN, f = 1 MHz	_	2	_	Ω
Switching time (rise time)	t <sub>r</sub>	See Figure 6.2.1	_	70	_	ns
Switching time (turn-on time)	t <sub>on</sub>		_	130	_	
Switching time (fall time)	t <sub>f</sub>		_	10	_	
Switching time (turn-off time)	t <sub>off</sub>		_	270	_	
MOSFET dv/dt ruggedness	dv/dt	V <sub>DD</sub> = 0 to 400 V, I <sub>D</sub> = 24.6 A	50	_	_	V/ns

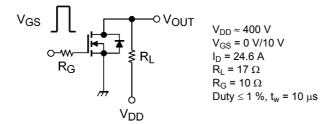


Fig. 6.2.1 Switching Time Test Circuit

# 6.3. Gate Charge Characteristics (T<sub>a</sub> = 25°C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Total gate charge (gate-source plus gate-drain)	$Q_g$	$V_{DD} \approx 400 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 49.2 \text{ A}$	-	160		nC
Gate-source charge 1	Q <sub>gs1</sub>		_	40	_	
Gate-drain charge	$Q_{gd}$		-	60		

# 6.4. Source-Drain Characteristics (T<sub>a</sub> = 25°C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Diode forward voltage	$V_{DSF}$	I <sub>DR</sub> = 49.2 A, V <sub>GS</sub> = 0 V	1	_	-1.7	V
Reverse recovery time	t <sub>rr</sub>	I <sub>DR</sub> = 24.6 A, V <sub>GS</sub> = 0 V		500		ns
Reverse recovery charge	$Q_{rr}$	-dI <sub>DR</sub> /dt = 50 A/μs	_	7	_	μС
Peak reverse recovery current	I <sub>rr</sub>		_	25	_	Α
Diode dv/dt ruggedness	dv/dt	$I_{DR} = 24.6 \text{ A}, V_{GS} = 0 \text{ V}, V_{DD} = 400 \text{ V}$	15	_	_	V/ns



# 7. Marking (Note)

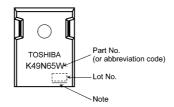


Fig. 7.1 Marking

Note: A line under a Lot No. identifies the indication of product Labels.

Not underlined: [[Pb]]/INCLUDES > MCV

Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product.

The RoHS is the Directive 2011/65/EU of the European Parliament and of the Council of 8 June 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

Rev.2.0

### 8. Characteristics Curves (Note)

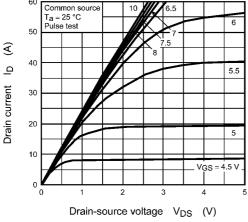
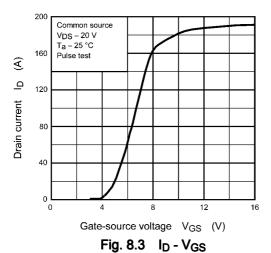


Fig. 8.1 I<sub>D</sub> - V<sub>DS</sub>



Drain-source voltage V<sub>DSS</sub> 600 550 **└** -100 Ambient temperature Ta (°C)

800

750

700

650

3

Common source VGS = 0 V ID = 10 mA

Fig. 8.5 V<sub>DSS</sub> - T<sub>a</sub>

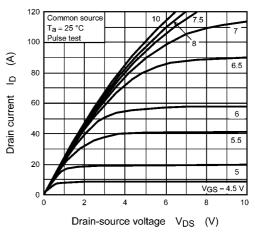


Fig. 8.2 I<sub>D</sub> - V<sub>DS</sub>

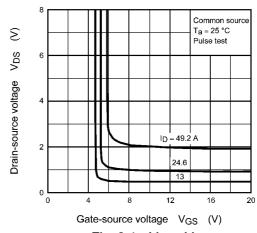


Fig. 8.4 V<sub>DS</sub> - V<sub>GS</sub>

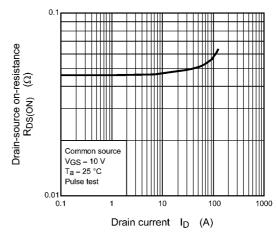


Fig. 8.6  $R_{DS(ON)}$  -  $I_D$ 

100000

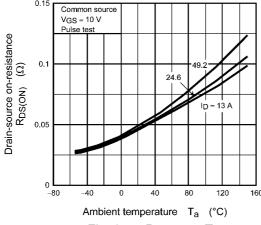
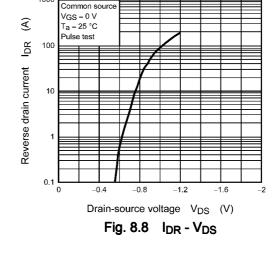


Fig. 8.7 R<sub>DS(ON)</sub> - T<sub>a</sub>





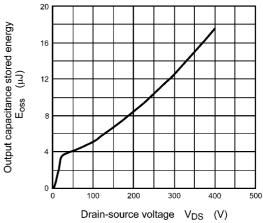


Fig. 8.10 E<sub>OSS</sub> - V<sub>DS</sub>

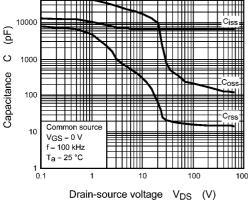


Fig. 8.9 C - V<sub>DS</sub>

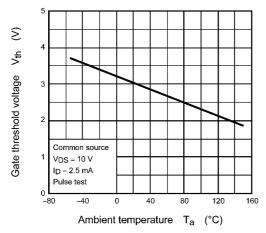


Fig. 8.11 V<sub>th</sub> - T<sub>a</sub>

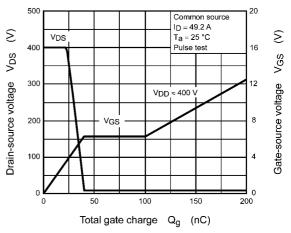


Fig. 8.12 Dynamic Input/Output Characteristics

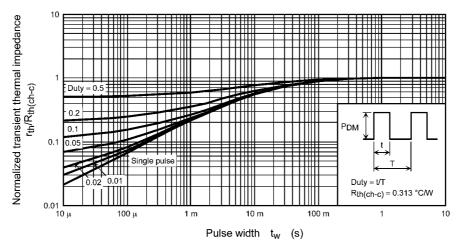


Fig. 8.13 r<sub>th</sub> - t<sub>w</sub> (Guaranteed Maximum)

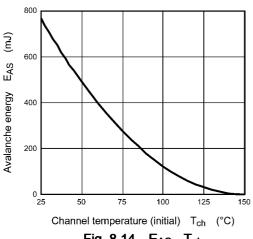


Fig. 8.14 E<sub>AS</sub> - T<sub>ch</sub> (Guaranteed Maximum)

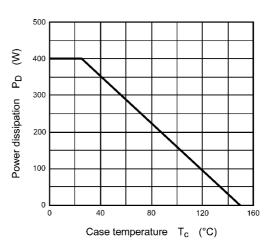


Fig. 8.15 P<sub>D</sub> - T<sub>c</sub> (Guaranteed Maximum)

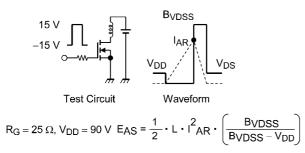


Fig. 8.16 Test Circuit/Waveform

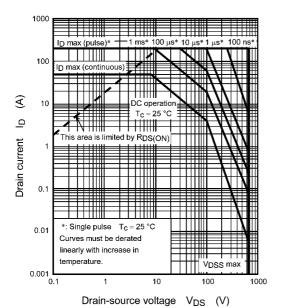


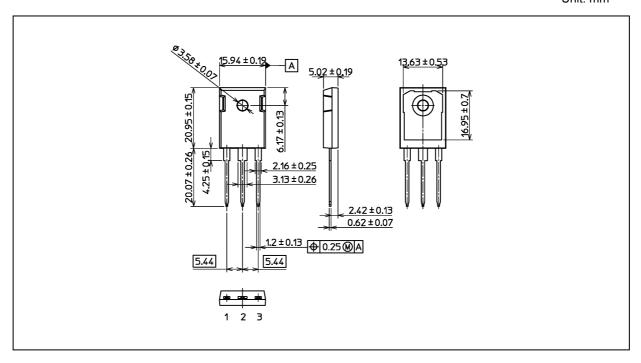
Fig. 8.17 Safe Operating Area (Guaranteed Maximum)

Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



# **Package Dimensions**

Unit: mm



Weight: 6.15 g (typ.)

Package Name(s)
JEITA: SC-65
TOSHIBA: 2-16L1A
Nickname: TO-247



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